

## UT8205AZ

Preliminary

Power MOSFET

## N-CHANNEL ENHANCEMENT MODE

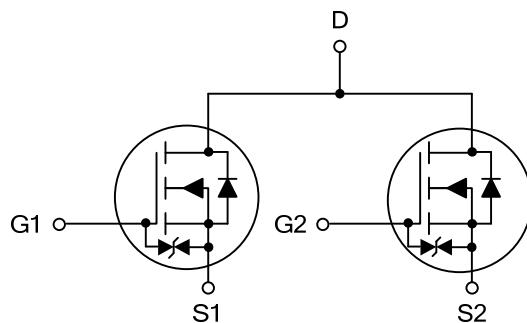
## ■ DESCRIPTION

The **UT8205AZ** uses advanced technology to provide fast switching, low on-resistance and cost-effectiveness. This device is suitable for all commercial-industrial surface mount applications.

## ■ FEATURES

- \*  $R_{DS(ON)} \leq 28m\Omega$  @  $V_{GS} = 4.5V$
- \* Ultra low gate charge ( typical 23 nC )
- \* Low reverse transfer Capacitance (  $C_{RSS} =$  typical 150 pF )
- \* Fast switching capability
- \* Avalanche energy Specified
- \* Improved dv/dt capability, high ruggedness

## ■ SYMBOL

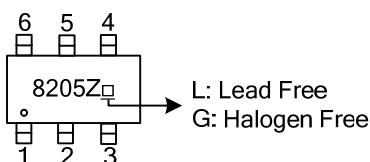


## ■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen-Free		1	2	3	4	5	6	7	8	
UT8205AZL-AG6-R	UT8205AZG-AG6-R	SOT-26	S1	D	S2	G2	D	G1	-	-	Tape Reel
UT8205AZL-S08-R	UT8205AZG-S08-R	SOP-8	D	S1	S1	G1	G2	S2	S2	D	Tape Reel
UT8205AZL-P08-R	UT8205AZG-P08-R	TSSOP-8	D	S1	S1	G1	G2	S2	S2	D	Tape Reel

UT8205AZL-AG6-R	(1) Packing Type (2) Package Type (3) Lead Plating	(1) R: Tape Reel  (2) AG6: SOT-26, P08: TSSOP-8, S08: SOP-8  (3) L: Lead Free, G: Halogen Free
-----------------	--	--

## ■ MARKING FOR SOT-26



### ■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS		UNIT
Drain-Source Voltage		$V_{DSS}$	20		V
Gate-Source Voltage		$V_{GSS}$	$\pm 12$		V
Drain Current (Note 2)	Continuous	$I_D$	6	A	A
	Pulsed	$I_{DM}$	20		A
Power Dissipation ( $T_A=25^\circ\text{C}$ ) (Note 3)	SOT-26	$P_D$	1.14	W	W
	SOP-8		1.6		W
	TSSOP-8		1		W
Junction Temperature		$T_J$	+150		$^\circ\text{C}$
Storage Temperature		$T_{STG}$	-55 ~ +150		$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse Test : Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$

3. Pulse width limited by  $T_{J(\text{MAX})}$

### ■ THERMAL DATA

PARAMETER		SYMBOL	MIN	TYP	MAX	UNIT
Junction to Ambient (Note)	SOT-26	$\theta_{JA}$			110	$^\circ\text{C/W}$
	SOP-8				78	$^\circ\text{C/W}$
	TSSOP-8				125	$^\circ\text{C/W}$

Note: Pulse Test : Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$

### ■ ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0\text{V}$ , $I_D=250\mu\text{A}$	20			V
Breakdown Voltage Temperature Coefficient	$\frac{\Delta BV_{DSS}}{\Delta T_J}$	$I_D=1\text{mA}$ , Reference to $25^\circ\text{C}$		0.03		$\text{V}/^\circ\text{C}$
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=20\text{V}$ , $V_{GS}=0\text{V}$ ,			1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 8\text{V}$			$\pm 10$	$\mu\text{A}$
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{DS}=V_{GS}$ , $I_D=250\mu\text{A}$	0.5		1.5	V
Drain-Source On-State Resistance (Note)	$R_{DS(\text{ON})}$	$V_{GS}=4.5\text{V}$ , $I_D=6.0\text{A}$			28	$\text{m}\Omega$
		$V_{GS}=2.5\text{V}$ , $I_D=5.2\text{A}$			38	$\text{m}\Omega$
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{ISS}$	$V_{DS}=20\text{V}$ , $V_{GS}=0\text{V}$ , $f=1.0\text{MHz}$		1035		pF
Output Capacitance	$C_{OSS}$			320		pF
Reverse Transfer Capacitance	$C_{RSS}$			150		pF
<b>SWITCHING PARAMETERS</b>						
Turn-ON Delay Time (Note)	$t_{D(\text{ON})}$	$V_{GS}=5\text{V}$ , $V_{DS}=10\text{V}$ , $R_D=10\Omega$ , $R_G=6\Omega$ , $I_D=1\text{A}$		30		ns
Turn-ON Rise Time	$t_R$			70		ns
Turn-OFF Delay Time	$t_{D(\text{OFF})}$			40		ns
Turn-OFF Fall-Time	$t_F$			65		ns
Total Gate Charge (Note)	$Q_G$	$V_{DS}=20\text{V}$ , $V_{GS}=5\text{V}$ , $I_D=6.0\text{A}$		23		nC
Gate Source Charge	$Q_{GS}$			4.5		nC
Gate Drain Charge	$Q_{GD}$			7		nC
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Drain-Source Diode Forward Voltage (Note)	$V_{SD}$	$I_S=1.7\text{A}$ , $V_{GS}=0\text{V}$			1.2	V
Diode Continuous Forward Current	$I_S$	$V_D=V_G$ , $V_S=1.3\text{V}$			1.54	A

Note: Surface mounted on 1 in<sup>2</sup> copper pad of FR4 board.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.